

N-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY			
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A) ^{a, e}	Q _g (Typ.)
20	0.044 at V _{GS} = 4.5 V	4.5	6.8 nC
	0.050 at V _{GS} = 2.5 V	4.2	
	0.056 at V _{GS} = 1.8 V	4.0	
	0.070 at V _{GS} = 1.5 V	1.5	

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- Compliant to RoHS Directive 2002/95/EC

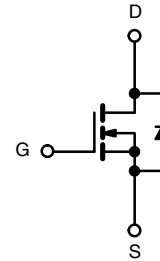
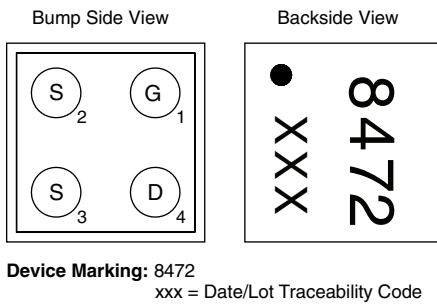


RoHS
COMPLIANT
HALOGEN
FREE

APPLICATIONS

- Baseband Switch
- DC/DC Conversion
 - Boost Converters
- Smart Phones, Portable Media Players

MICRO FOOT



N-Channel MOSFET

Ordering Information: Si8472DB-T2-E1 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)				
Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	20	V	
Gate-Source Voltage	V _{GS}	± 8		
Continuous Drain Current (T _J = 150 °C)	I _D	T _A = 25 °C	4.5 ^a	A
		T _A = 70 °C	3.6 ^a	
		T _A = 25 °C	3.3 ^b	
		T _A = 70 °C	2.6 ^b	
Pulsed Drain Current (t = 300 μs)	I _{DM}	20		
Continuous Source-Drain Diode Current	I _S	T _C = 25 °C	1.5 ^a	
		T _A = 25 °C	0.65 ^b	
Maximum Power Dissipation	P _D	T _A = 25 °C	1.8 ^a	W
		T _A = 70 °C	1.1 ^a	
		T _A = 25 °C	0.78 ^b	
		T _A = 70 °C	0.5 ^b	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	- 55 to 150	°C	
Package Reflow Conditions ^c	VPR	260		
	IR/Convection	260		

Notes:

- Surface mounted on 1" x 1" FR4 board with full copper, t = 10 s.
- Surface mounted on 1" x 1" FR4 board with minimum copper, t = 10 s.
- Refer to IPC/JEDEC (J-STD-020C), no manual or hand soldering.
- In this document, any reference to case represents the body of the MICRO FOOT device and foot is the bump.
- Based on T_A = 25 °C.

THERMAL RESISTANCE RATINGS

Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^{a, b}	$t = 10 \text{ s}$	R_{thJA}	55	70	°C/W
Maximum Junction-to-Ambient ^{c, d}	$t = 10 \text{ s}$		125	160	

Notes:

- a. Surface mounted on 1" x 1" FR4 board with full copper.
b. Maximum under steady state conditions is 100 °C/W.
c. Surface mounted on 1" x 1" FR4 board with minimum copper.
d. Maximum under steady state conditions is 190 °C/W.

SPECIFICATIONS ($T_J = 25 \text{ °C}$, unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \text{ } \mu\text{A}$	20			V
V_{DS} Temperature Coefficient	$\Delta V_{DS}/T_J$	$I_D = 250 \text{ } \mu\text{A}$		16		mV/°C
$V_{GS(th)}$ Temperature Coefficient	$\Delta V_{GS(th)}/T_J$		-2.6			
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250 \text{ } \mu\text{A}$	0.4		0.9	V
Gate-Source Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}$			1	μA
		$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 70 \text{ °C}$			10	
On-State Drain Current ^a	$I_{D(on)}$	$V_{DS} \leq -5 \text{ V}, V_{GS} = 4.5 \text{ V}$	10			A
Drain-Source On-State Resistance ^a	$R_{DS(on)}$	$V_{GS} = 4.5 \text{ V}, I_D = 1.5 \text{ A}$		0.036	0.044	Ω
		$V_{GS} = 2.5 \text{ V}, I_D = 1 \text{ A}$		0.041	0.050	
		$V_{GS} = 1.8 \text{ V}, I_D = 1 \text{ A}$		0.046	0.056	
		$V_{GS} = 1.5 \text{ V}, I_D = 0.5 \text{ A}$		0.050	0.070	
Forward Transconductance ^a	g_{fs}	$V_{DS} = 10 \text{ V}, I_D = 1.5 \text{ A}$		16		S
Dynamic^b						
Input Capacitance	C_{iss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		630		pF
Output Capacitance	C_{oss}		105			
Reverse Transfer Capacitance	C_{rss}		42			
Total Gate Charge	Q_g	$V_{DS} = 10 \text{ V}, V_{GS} = 8 \text{ V}, I_D = 1.5 \text{ A}$		12	18	nC
				6.8	11	
Gate-Source Charge	Q_{gs}	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 1.5 \text{ A}$		0.8		
Gate-Drain Charge	Q_{gd}		1.1			
Gate Resistance	R_g	$V_{GS} = 0.1 \text{ V}, f = 1 \text{ MHz}$		5.3		Ω
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = -10 \text{ V}, R_L = 6.7 \text{ } \Omega$ $I_D \cong 1.5 \text{ A}, V_{GEN} = -4.5 \text{ V}, R_g = 1 \text{ } \Omega$		7	15	ns
Rise Time	t_r		15	30		
Turn-Off Delay Time	$t_{d(off)}$		30	60		
Fall Time	t_f		10	20		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = -10 \text{ V}, R_L = 6.7 \text{ } \Omega$ $I_D \cong -1.5 \text{ A}, V_{GEN} = -8 \text{ V}, R_g = 1 \text{ } \Omega$		5	10	
Rise Time	t_r		15	30		
Turn-Off Delay Time	$t_{d(off)}$		30	60		
Fall Time	t_f		10	20		



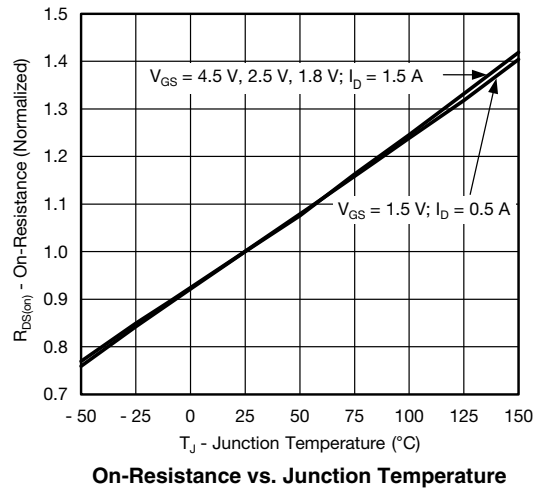
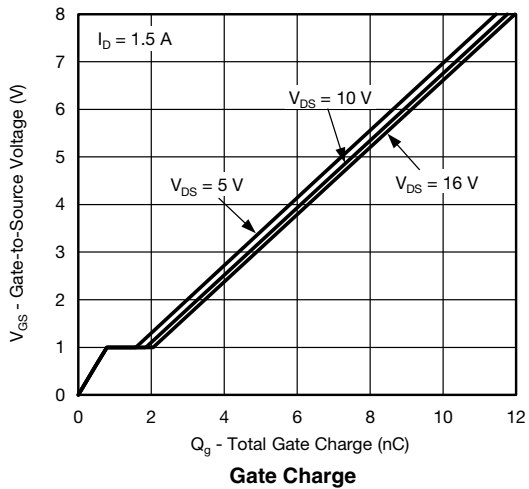
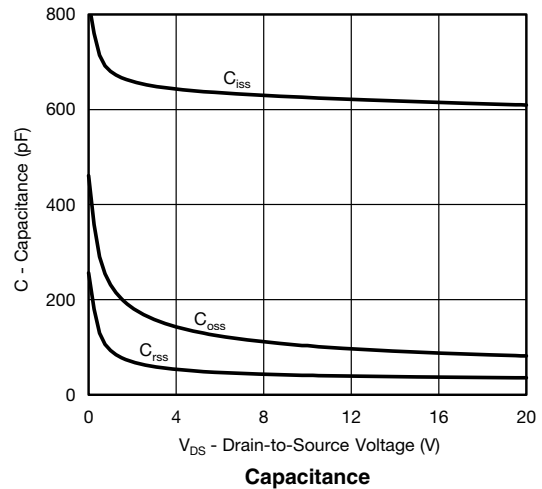
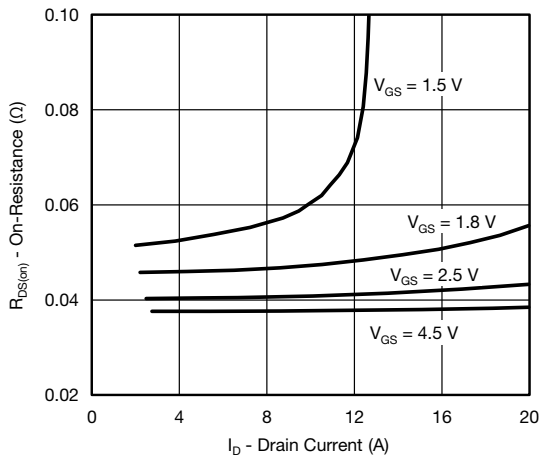
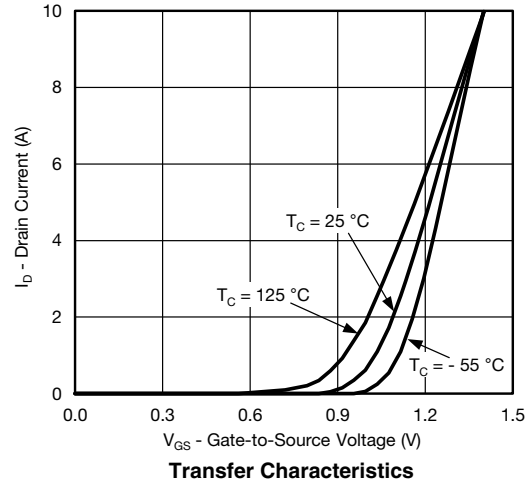
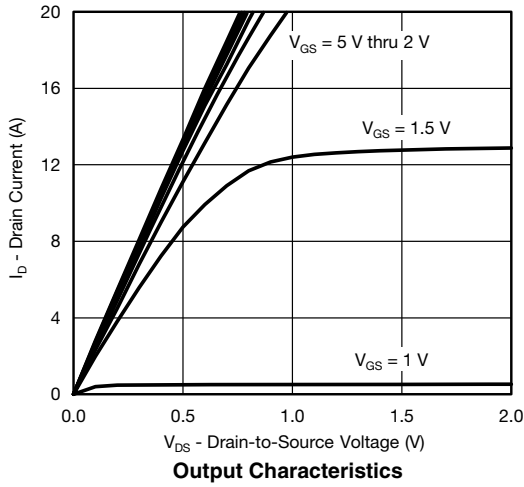
SPECIFICATIONS ($T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted)						
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Drain-Source Body Diode Characteristics						
Continuous Source-Drain Diode Current	I_S	$T_A = 25\text{ }^\circ\text{C}$			1.5	A
Pulse Diode Forward Current	I_{SM}				20	
Body Diode Voltage	V_{SD}	$I_S = 1.5\text{ A}, V_{GS} = 0$		0.7	1.2	V
Body Diode Reverse Recovery Time	t_{rr}	$I_F = 1.5\text{ A}, dI/dt = 100\text{ A}/\mu\text{s}, T_J = 25\text{ }^\circ\text{C}$		15	30	ns
Body Diode Reverse Recovery Charge	Q_{rr}			6	15	nC
Reverse Recovery Fall Time	t_a			7		ns
Reverse Recovery Rise Time	t_b			8		

Notes:

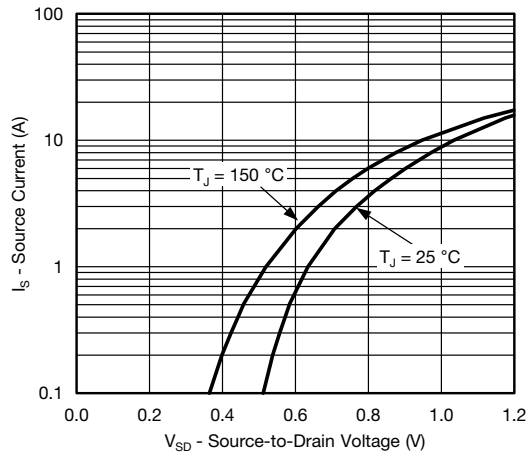
- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

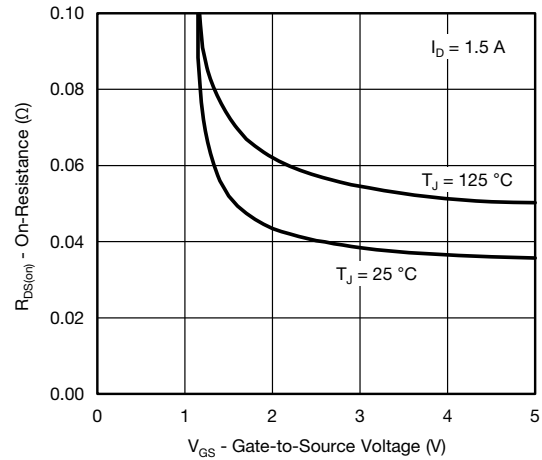
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



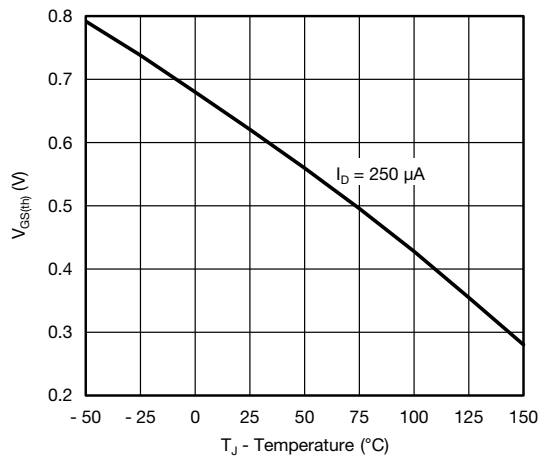
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



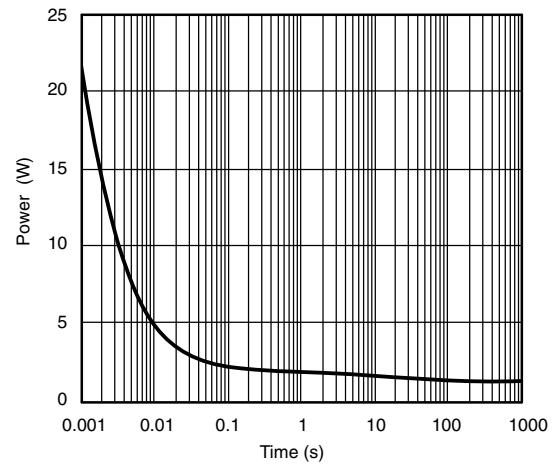
Source-Drain Diode Forward Voltage



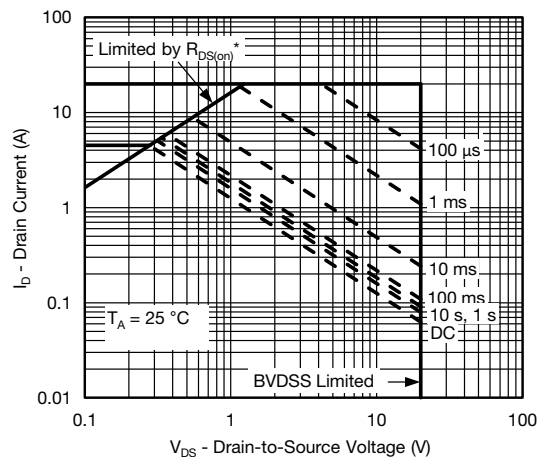
On-Resistance vs. Gate-to-Source Voltage



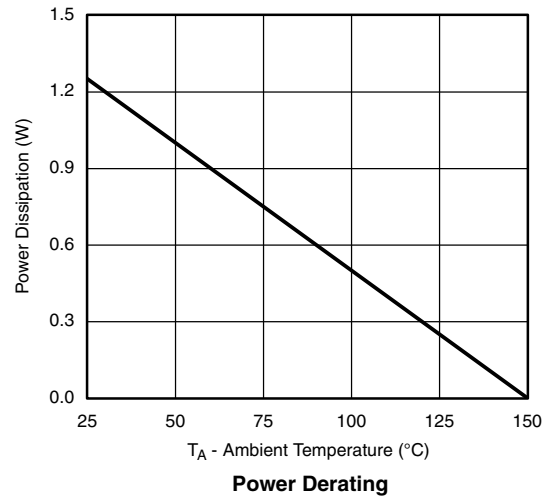
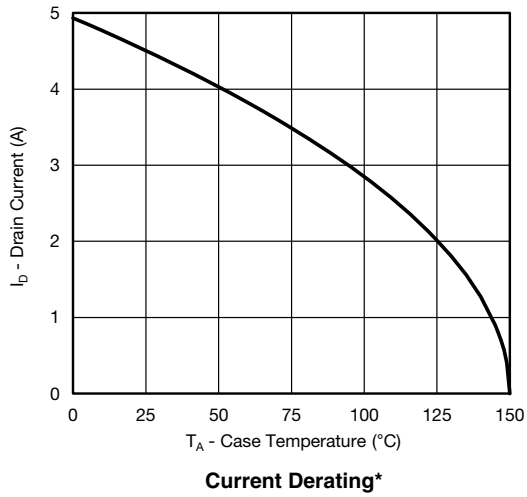
Threshold Voltage



Single Pulse Power, Junction-to-Ambient



Safe Operating Area, Junction-to-Ambient
* $V_{GS} >$ minimum V_{GS} at which $R_{DS(on)}$ is specified

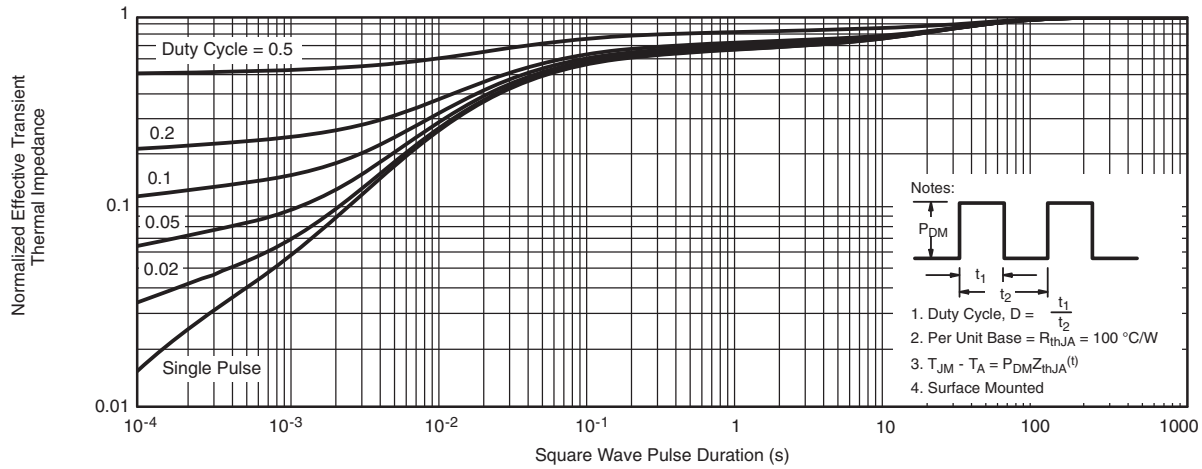
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)


Note:

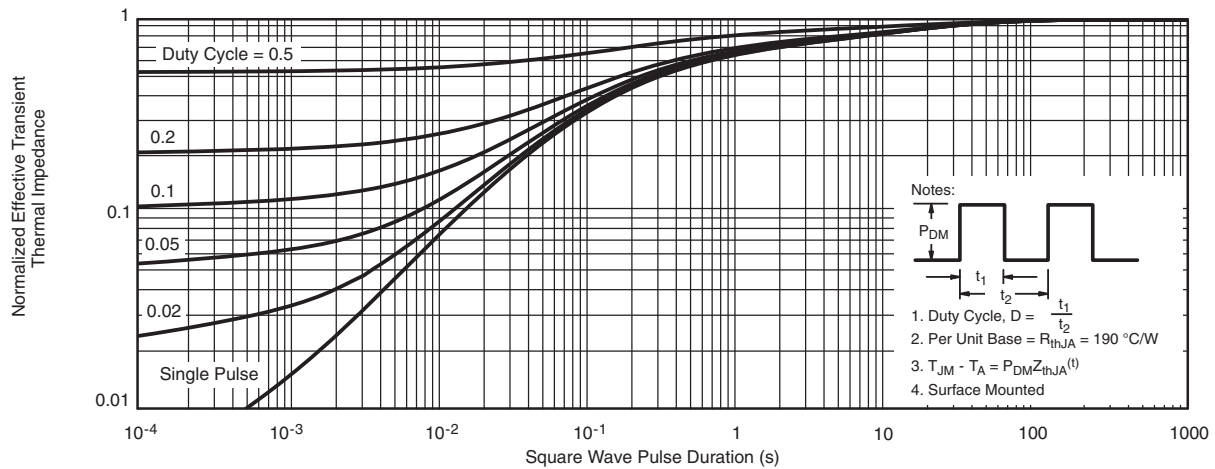
When Mounted on 1" x 1" FR4 with Full Copper.

* The power dissipation P_D is based on $T_{J(max)} = 150$ °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



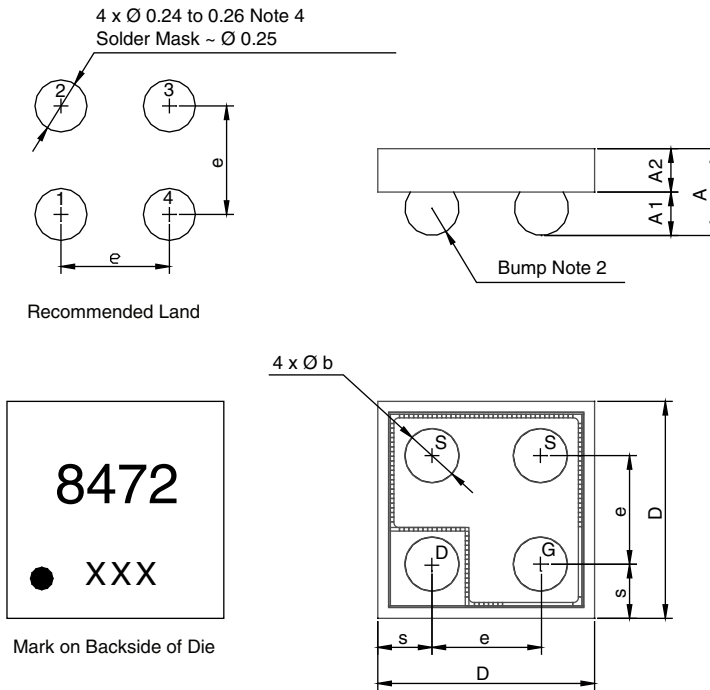
Normalized Thermal Transient Impedance, Junction-to-Ambient (1" x 1" FR4 Board with Full Copper)



Normalized Thermal Transient Impedance, Junction-to-Ambient (1" x 1" FR4 Board with Minimum Copper)

PACKAGE OUTLINE

MICRO FOOT 1 mm x 1 mm: 4-BUMP (2 x 2, 0.5 mm PITCH)



Notes (Unless otherwise specified):

1. All dimensions are in millimeters.
2. Four (4) solder bumps are lead (Pb)-free 95.5Sn/3.8Ag/0.7Cu with diameter \varnothing 0.30 mm to 0.32 mm.
3. Backside surface is coated with a Ti/Ni/Ag layer.
4. Non-solder mask defined copper landing pad.
5. • is location of pin 1.

Dim.	Millimeters ^a			Inches		
	Min.	Nom.	Max.	Min.	Nom.	Max.
A	0.462	0.505	0.548	0.0181	0.0198	0.0215
A ₁	0.220	0.250	0.280	0.0086	0.0098	0.0110
A ₂	0.242	0.255	0.268	0.0095	0.0100	0.0105
b	0.300	0.310	0.320	0.0118	0.0122	0.0126
e	0.500			0.0197		
s	0.230	0.250	0.270	0.0090	0.0098	0.0106
D	0.920	0.960	1.000	0.0362	0.0378	0.0394

Notes:

- a. Use millimeters as the primary measurement.

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- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.